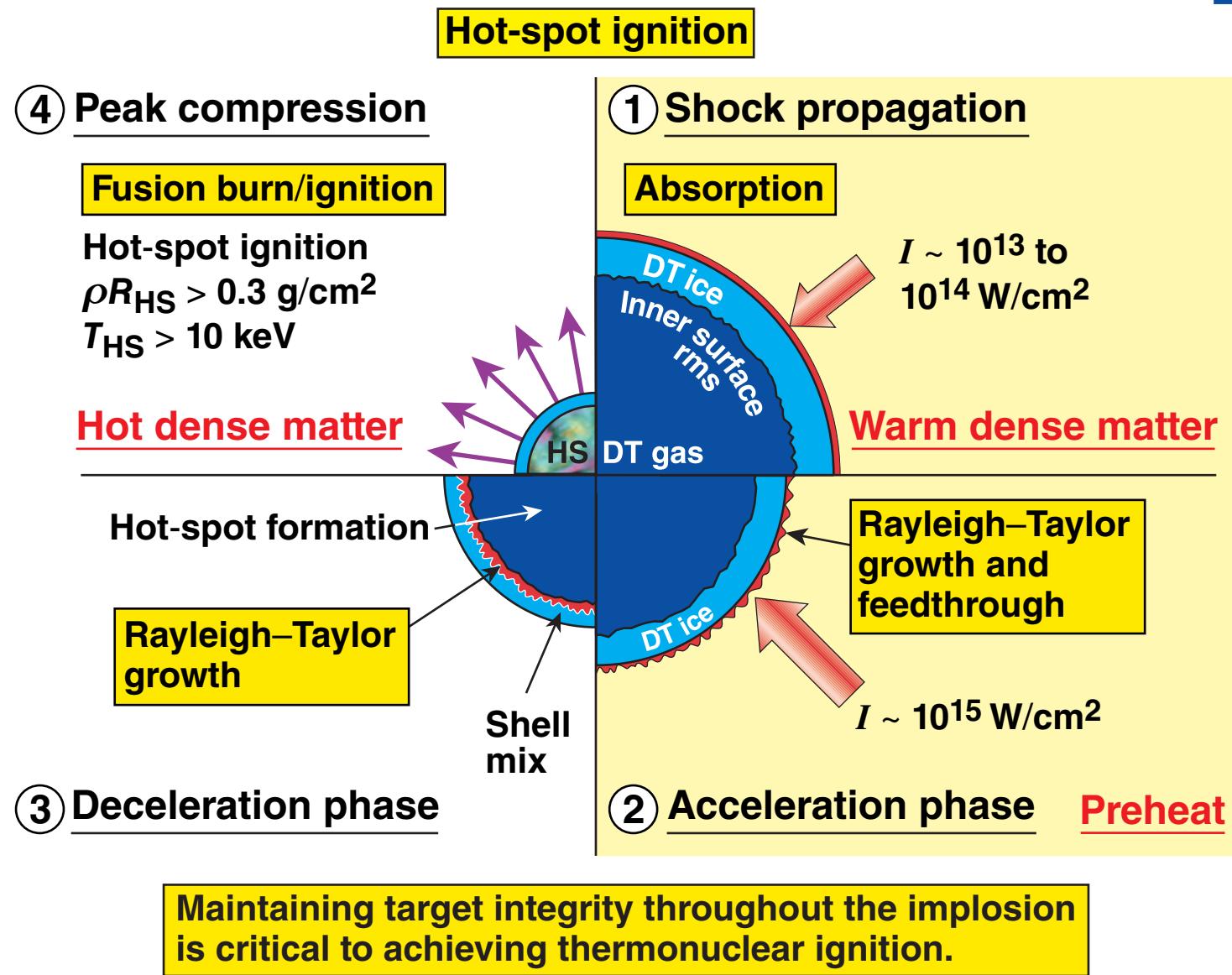


The stages of an inertial confinement fusion (ICF) implosion



Introduction to the Rayleigh–Taylor instability



- Rayleigh–Taylor instability (RTI)
 - instability at the interface of fluids with different densities when a lighter fluid supports a heavier fluid
 - in ICF, RTI occurs during the acceleration and deceleration phases of the implosion
 - modulations grow exponentially early in time, then grow linearly after reaching the saturation level ($Z_k = \lambda/10$) with the growth rate given by*

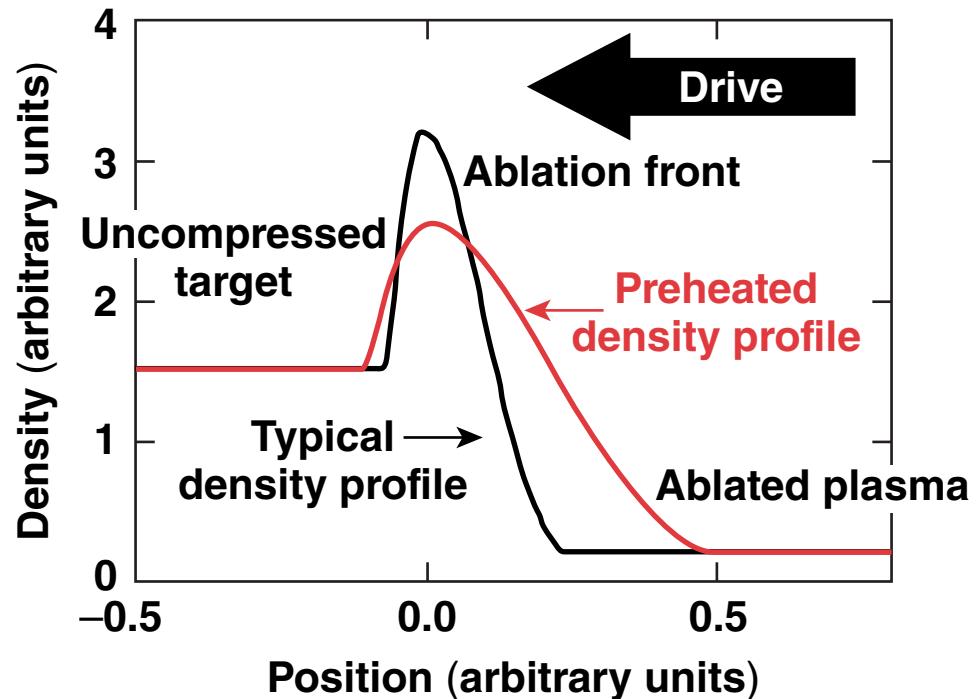
$$\gamma_{\text{RT}} = \alpha \sqrt{\frac{k \times g}{1 + k \times L_m}} - \beta \times k \times v_a^\dagger$$

Variable	Description
α	Constant
β	Constant
k	Modulation wave number
g	Interface acceleration
v_a	Ablation velocity
L_m	Density scale length

*S. W. Haan, Phys. Rev. A **39**, 5812 (1989).

†R. Betti, Phys. Plasmas **5**, 1446 (1998).

Previous RT experiments demonstrated decreased instability growth at peak laser intensities of $1 \times 10^{15} \text{ W/cm}^2$ in CH targets caused by electron preheat*



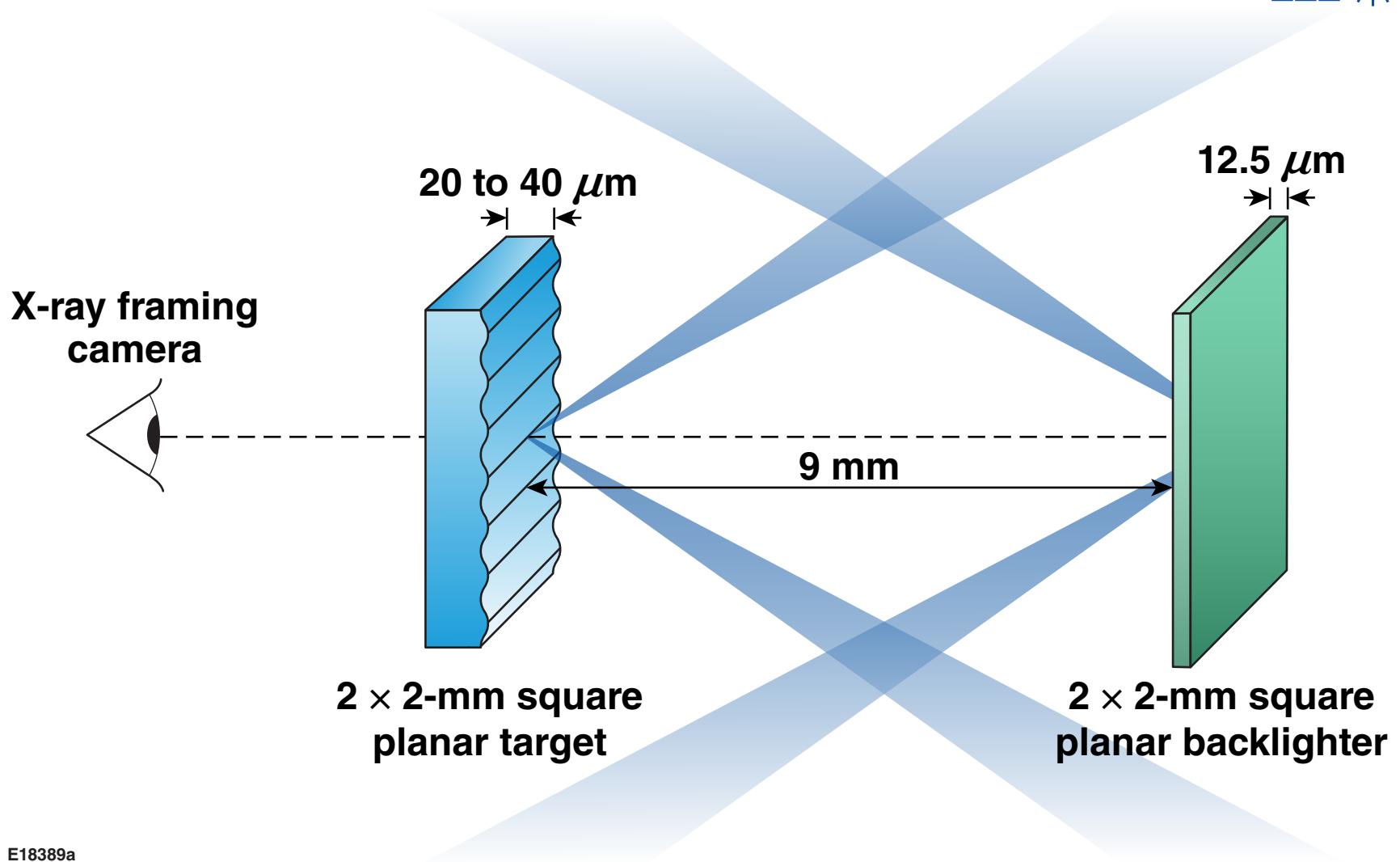
$$\gamma_{\text{RT}} = \alpha \cdot \sqrt{\frac{k \cdot g}{1 + k \cdot L_m}} - \beta \cdot k \cdot V_a \quad **$$

Target preheat leads to increased density scale length (L_m) and ablation velocity (V_a), resulting in decreased RT modulation growth.

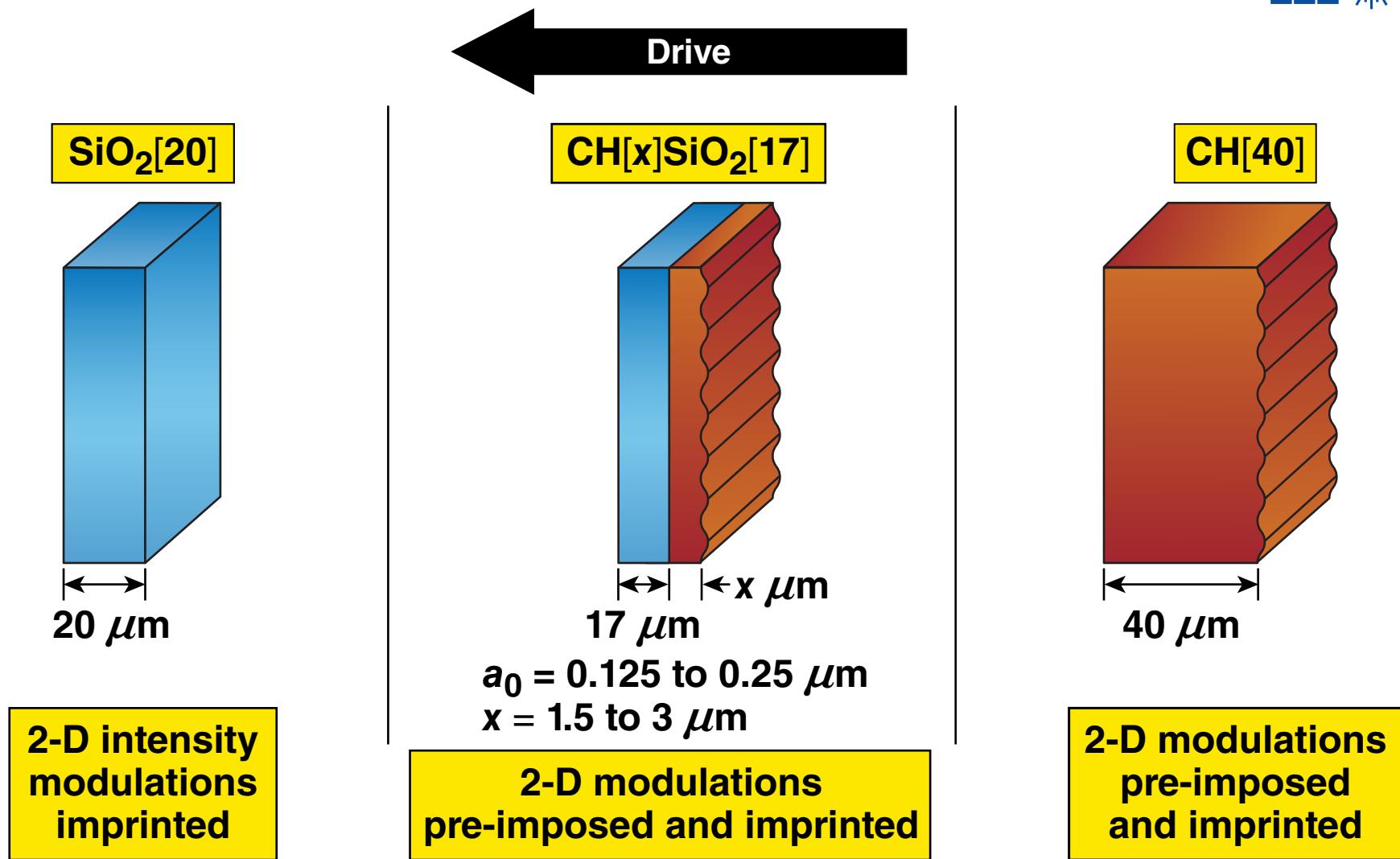
* V. A. Smalyuk et al. Phys. Plasmas 15, 082703 (2008).

** R. Betti et al., Phys. Plasmas 5, 1446 (1998).

Planar CH, SiO₂, and CH–SiO₂ targets are driven by 10 to 12 drive beams, while an x-ray backlighter is used to measure areal density modulation growth



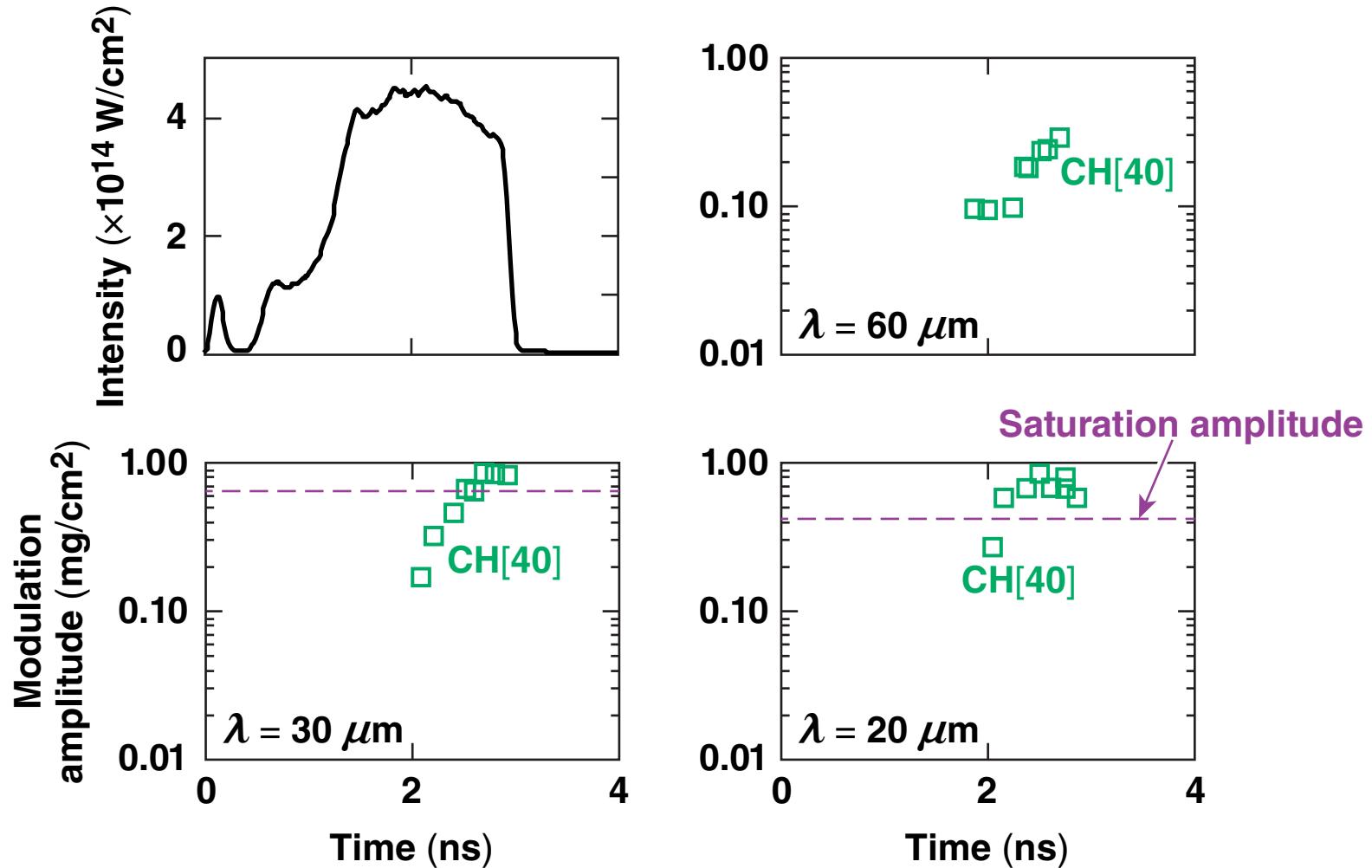
Targets were seeded with an intensity-imprinted 2-D modulation, while pre-imposed mass modulations were also used on CH and CH–SiO₂ targets



40- μm -thick CH targets driven at low intensities ($5 \times 10^{14} \text{ W/cm}^2$) show significant growth up to the modulation saturation amplitude



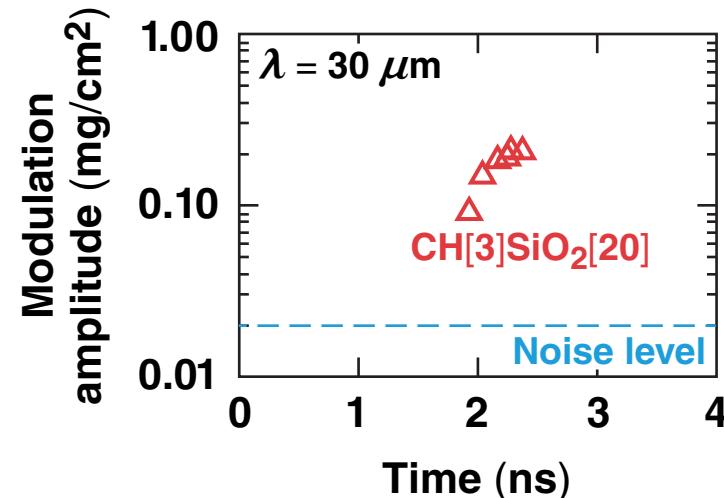
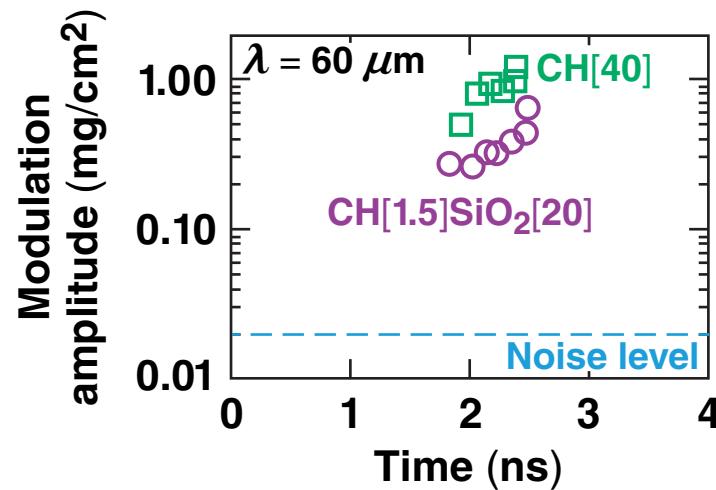
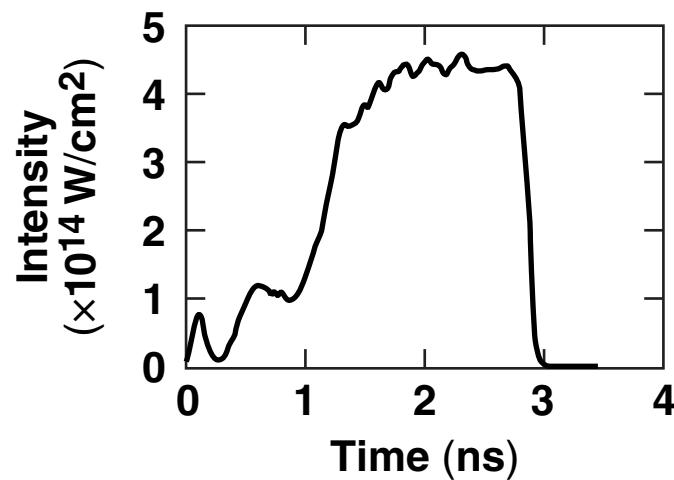
- Pre-imposed modulations



20- μm -thick intensity-imprinted SiO_2 targets with 1.5- and 3- μm CH ablators show modulation growth at low intensities



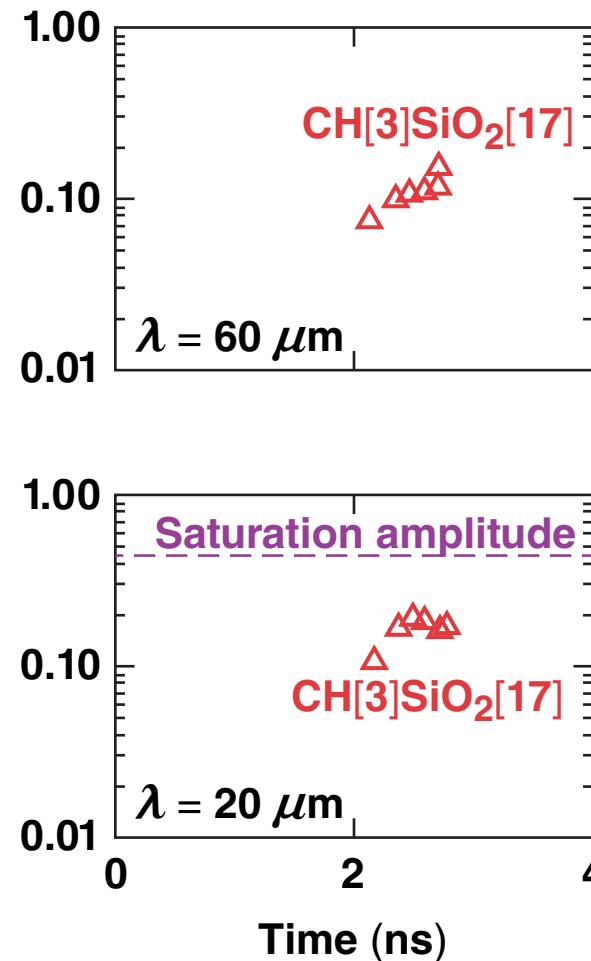
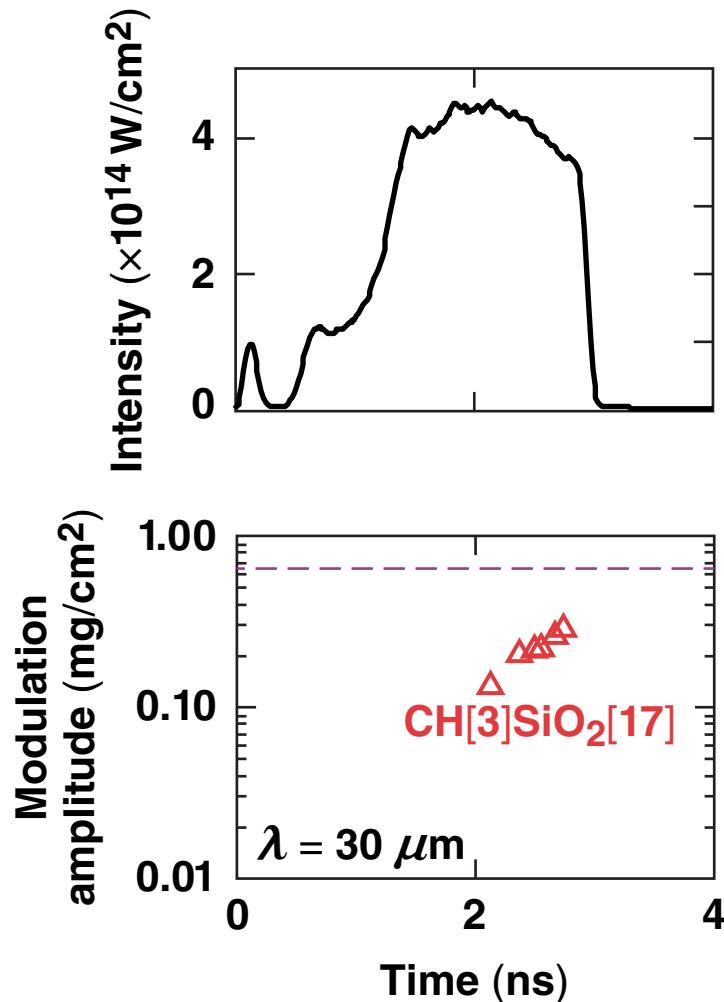
- Intensity-imprinted modulations



17- μm -thick SiO_2 targets with a perturbed 3- μm CH ablator show significant modulation growth in SiO_2 at low intensities



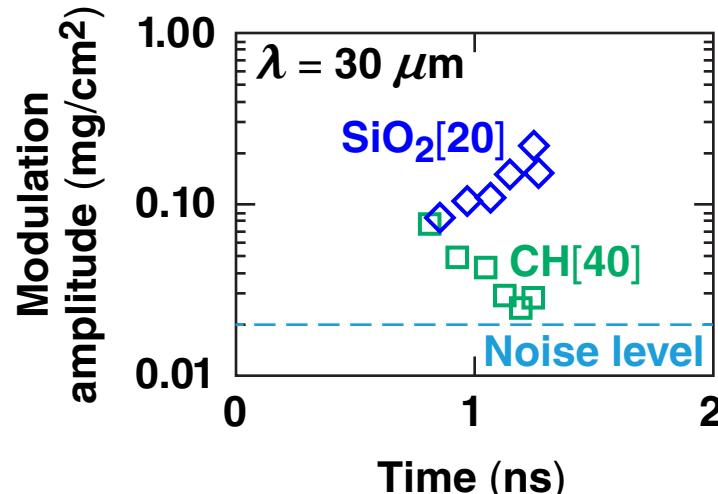
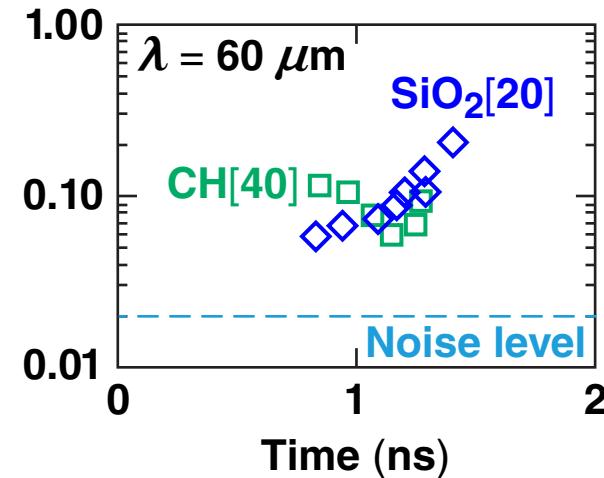
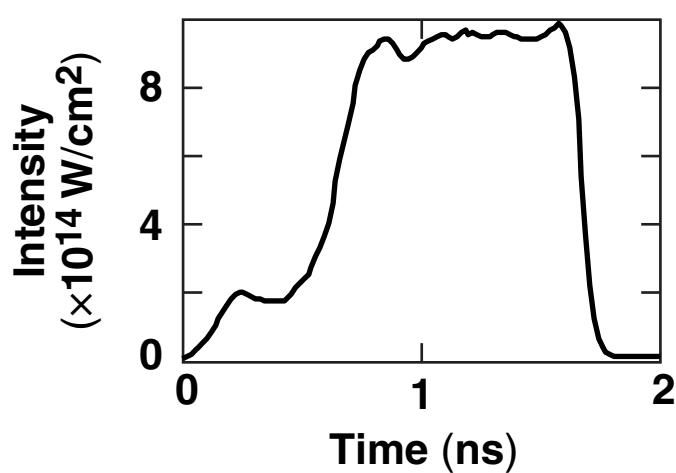
- Pre-imposed modulations



At high intensities ($1 \times 10^{15} \text{ W/cm}^2$) imprinted modulations grow in SiO_2 , while CH targets of comparable mass show no growth



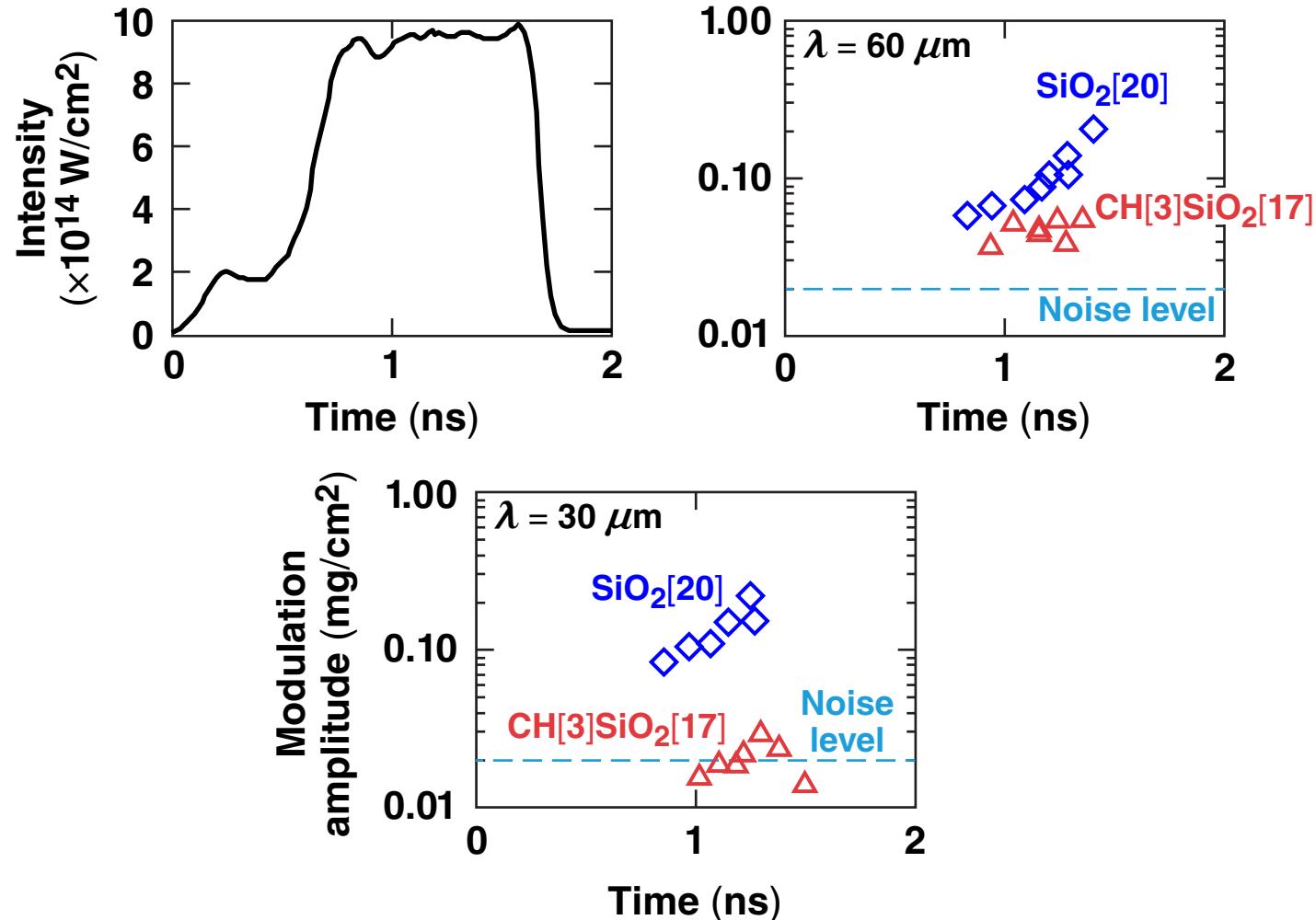
- Intensity-imprinted modulations



17- μm -thick SiO_2 targets with a perturbed 3- μm CH ablator show no significant instability growth at high intensities, while SiO_2 without CH shows significant modulation growth



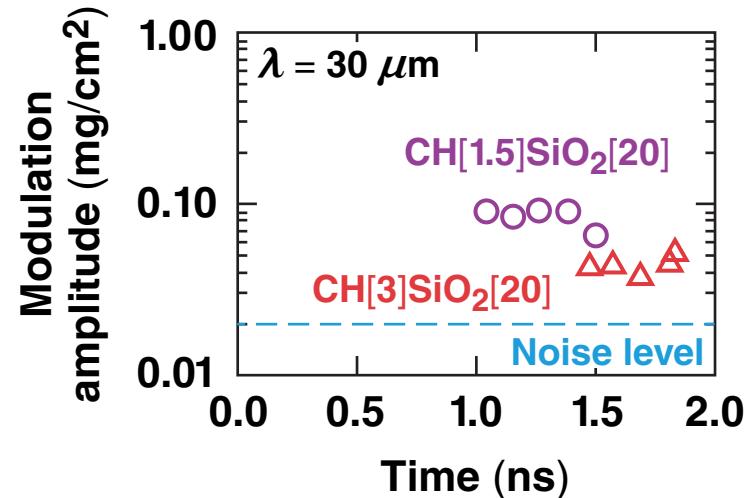
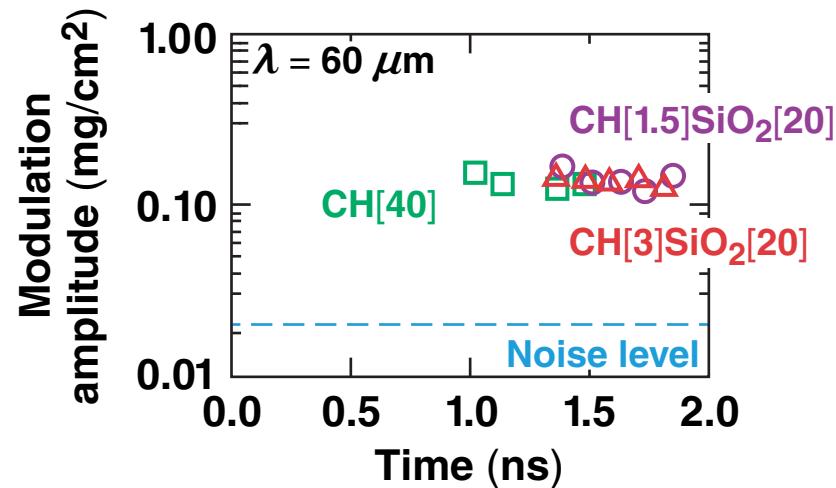
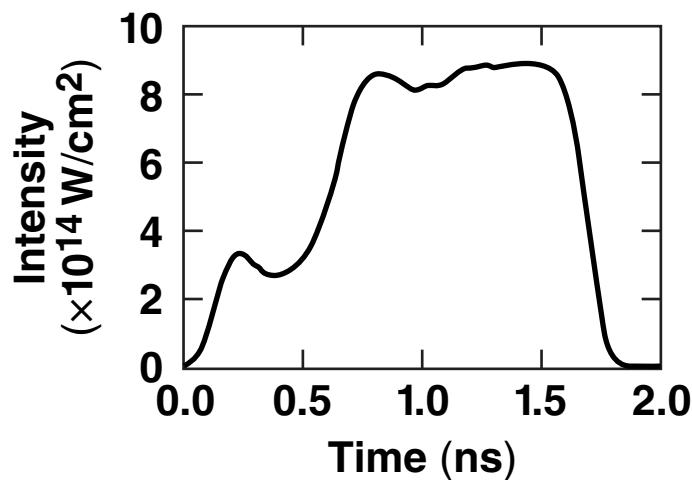
- Pre-imposed (CH-SiO_2) and imprinted (SiO_2) modulations



Intensity-imprinted targets with CH ablators show no significant modulation growth at high intensities



- Intensity-imprinted modulations



Summary/Conclusions

Rayleigh–Taylor (RT) experiments at $1 \times 10^{15} \text{ W/cm}^2$ with CH and SiO₂ ablators show significant growth differences



- At peak drive intensities of $5 \times 10^{14} \text{ W/cm}^2$, both CH and CH–SiO₂ targets show significant 2-D modulation growth
- At peak drive intensities of $1 \times 10^{15} \text{ W/cm}^2$
 - CH targets with 2-D modulations (pre-imposed and intensity imprinted) show a reduction in RT growth caused by electron preheat
 - SiO₂ targets with 2-D intensity-imprinted modulations show significant RT growth
 - CH–SiO₂ targets with 2-D modulations (pre-imposed and intensity imprinted) show a reduction in RT growth